Pseudo-gap and spin polarization in a two-dimensional electron gas

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Abstract.
Tunnelling density of states in the vicinity of Fermi level of a two-dimensional electron gas subjected to an external parallel and zeroth magnetic field is calculated. It reveals a pseudo-gap recently observed in the experiments. The gap originates in spin polarization of 2DEG. Non-monotonic dependence of energy on a Landau level filling factor (density) was obtained. It implies the tunneling current peculiarities at filling factors 1/2 and 1. The Ising-like model of the exchange interaction in 2DEG was exploited instead of the conventional one. It was crucial to achieve even a qualitative agreement with experimental data.

Introduction

The investigation of a two-dimensional (2DEG) is still in focus of modern physics. Lately spin effects attracted a great attention of researchers. Spontaneous spin polarization, partial as well as total one, along with a polarization induced by external magnetic field are widely discussed. Some peculiarities of tunneling current were observed recently. Evidently, they are closely connected with unusual behavior of density of states (DOS) by the Fermi level in 2DEG. There are two groups of experiments, the first one deals with parallel and zero magnetic field [1] and the second one investigates perpendicular magnetic field, that is, the regime of the Quantum Hall Effect [2-4].

Lately the tunneling spectroscopy revealed two peaks in DOS surrounding the lowered DOS at the Fermi level [4]. The authors treated this behavior as a manifestation of the Coulomb pseudo-gap predicted by Efros and Shklovskii long time ago. The crucial feature making this explanation doubtful is a dependence of the pseudo-gap shape upon external magnetic field. In the contrary, in the experiment [3] the observed peculiarities of DOS were regarded as an indication to spin polarization. Here the effect of spin polarization on the tunneling current is discussed. A similar approach was previously used to obtain a lowered DOS at the Fermi level in 1DEG [5] and 2DEG [6]. In particular, it results in a lower conductance step with respect to a conductance quantum in a quantum wire [5].

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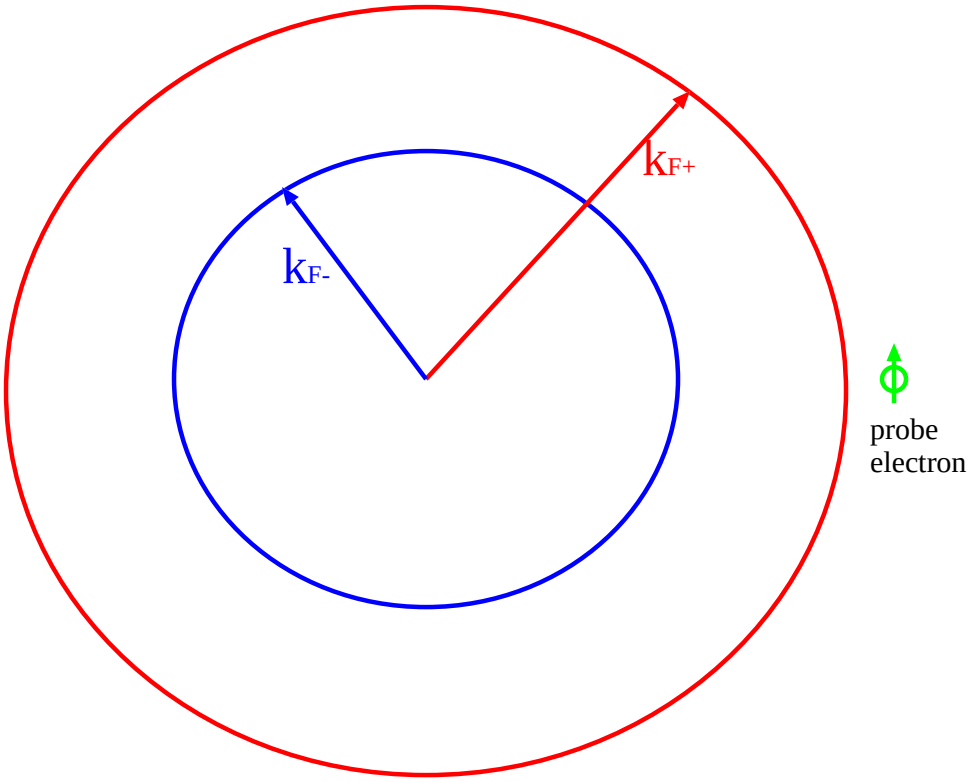
1 Exchange interaction model for zero and parallel magnetic field

Throughout the paper we employ the Ising model to describe the exchange interaction and therefore use the following relation to calculate the exchange energy

$$E_{ex} = \frac{e}{2} \sum_{kq \neq 0} V(q) n_k \, n_{k+q} + e \sum_{kq \neq 0} V(q) n_{k\,=+} \, n_{k+q\,=-} \qquad (1)$$

, where $n_k = 0,1$ is a filling factor of the electron state with the wave vector k and spin orientation $= +$ (up); $-$ (down), n is an electron sheet density, $V(q)$ is a 2D Fourier transform of the Coulomb potential. For the unscreened Coulomb potential $V(q) = 2\ e = q$, where is a permittivity.

The second term regarding the interaction between electrons with opposite spin orientation differences the Ising (I) model from that of Kohn-Sham (KS). The I-model turned out to be more adequate to the available experimental data.



Two-dimensional wave vector space

Figure 1: The 2D wave vector space with the Fermi wave vectors k_{F+} and k_{F-} for majority (+) and minority (−) spin polarization, respectively.

In Fig.1 the spin polarized state of a 2DEG is depicted.

The total energy should acquire the Zeeman term if the 2DEG is embedded in the external magnetic field B.

$$E_B = \frac{1}{2} g_0 \ _B B \Big(\sum_{k=+} n_k - \sum_{k=-} n_k \Big) \tag{2}$$

The ground state of the system comprising filling factors $n_k = 0$ or 1 for the fixed electron sheet density $n = n_+ + n_-$ is obtained on minimizing the total energy including kinetic, direct Coulomb, exchange, and magnetic energy. The correlation energy was ignored as the leading term was supposed to be that of exchange. At least, an exchange interaction was sufficient to qualitatively explain a pseudo-gap shape and its dependence on a magnetic field.

2 Tunnelling density of states

Here we only refer to the tunnelling density of states (TDOS) $D(")$ which could be obtained in tunnel spectroscopy experiments. The tunnel current between two electron reservoirs biased with a voltage V is supplied by a convolution (see, for instance, [4])

$$I \quad \int_{-1}^{+} D_l(") D_r(" - eV) [f_r(" - eV;T) - f_l(";T)] d" \tag{3}$$

Here f is the Fermi distribution function for temperature T, the subscript r corresponds to the right reservoir while the subscript l corresponds to the left one.

For spin-dependent tunneling one must employ the above expression separately for spin-up and spin-down electrons. When one reservoir is a metal or heavily doped semiconductor its DOS may be replaced by a constant. Then the DOS associated with the reservoir of 2DEG at zero temperature $T = 0$ can be obtained from a derivative $dI=dV$.

For weak tunneling events the electrons added to the system or removed from it do not much disturb the state of the system. The tunnel DOS could thus be calculated in the following way. Firstly, one should calculate the energy $"(k;)$ required to add an electron into empty state $(k;)$ above the Fermi level or remove an electron from the occupied state $(k;)$ under the Fermi level. It corresponds to different bias polarity. The derivative $d"=dk$ gives the TDOS of 2DEG

$$D(") \quad kjd"=dkj^{-1}: \tag{4}$$

Worth mentioning the derivative $d"=dk$ may be large although the corrections to the energy caused by exchange interaction are small. One more remark is that calculations of $D(")$ should be done rather carefully as the reciprocal function $k(")$ could be manifold.

The exchange energy of a probe electron with a spin and a wave vector k is calculated according to the relation

$$"(k; =) = \sum_{q \neq 0} V(q) n_{k+q; =+} - \sum_{q \neq 0} V(q) n_{k+q; =-} \tag{5}$$

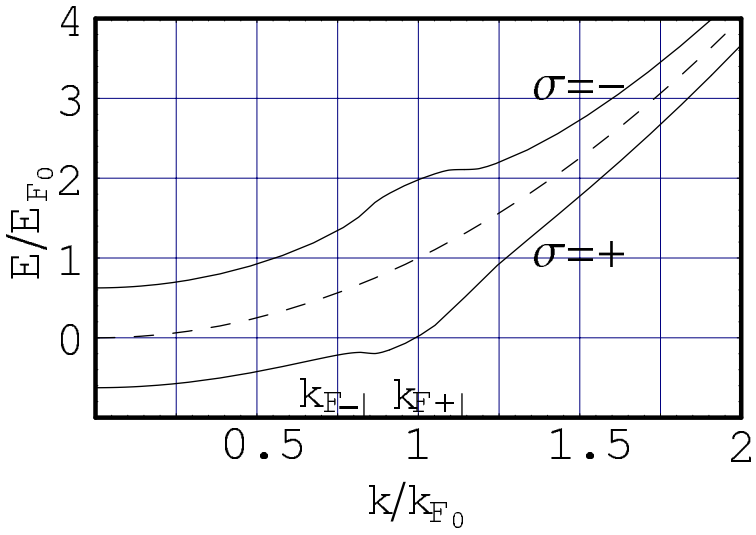


Figure 2: The calculated dependence of the probe electron energy on its wave vector.

,where lling factors $n_{k;}$ correspond to the ground state con guration. It is readily seen from above equation that the interaction with electrons of the major spin orientation in the interval $(k_{F+};k_{F})$ in 2D k-space determines the exchange energy. The exchange energy is thus roughly proportional to a polarization degree $jk_{F+} \quad k_{F} j$which depends on a magnetic eld.

In Fig.2 the calculated dependence of the probe electron energy on its wave vector for electron density $n = 1:5 \quad 10^{11}cm^{-2}$ and a magnetic eld $B = 2T$ for a 2DEG in GaAs/AlGaAs heterostructure is plotted. It exhibits the derivatives $d =dk = 0$ around both k_{F+} and k_{F} . This corresponds to the in nite density of states. Evidently, screening of Coulomb potential smoothens these singularities. However, these peculiarities explain the associated peculiarities in tunneling current observed in [1].

3 Perpendicular magnetic eld

We evaluated the dependence of energy of a 2DEG subject to a perpendicular magnetic eld on the Landau lling factor via the relations

$$( ) = \frac{h!_c}{2} \quad A^{3=2}\frac{e^2}{L}\exp(\ 1=2 \ ); \tag{6}$$

for $\frac{1}{2}$ (when electrons with the same spin polarization occupy the rst Landau level) and

$$( ) = \ (\ = 1=2) + (1=2)\frac{h!_c}{2}(\quad 1=2) + (A=2)^{1=2}\frac{e^2}{L}\exp(\quad)$$
$$A(\quad 1=2)^{3=2}\frac{e^2}{L}\exp(\ 1=2 \ (\quad 1=2)) \tag{7}$$

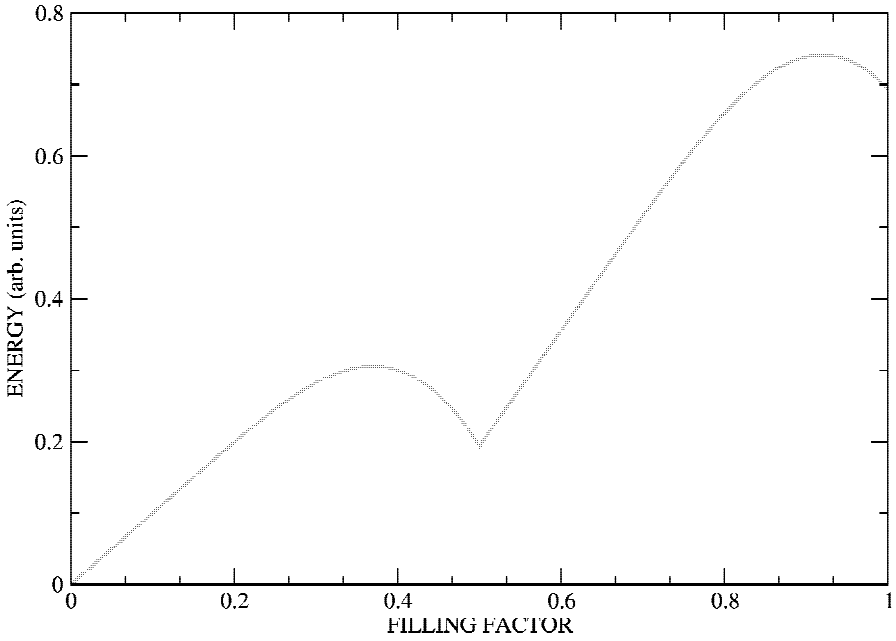


Figure 3: The dependence of 2DEG energy on the lling factor for B = 10T.

, for $\frac{1}{2}$ 1 (when electrons with the opposite spin polarization begin to occupy the rst Landau level), A is a numerical constant of the order order of unity. Here h and L are the cyclotron frequency and the quantum Larmore radius, respectively. In general, the Zeeman term analogous to that in Eq.(2) should be included. But it turned out to be small compared to the kinetic and exchange energies. The Fig.3 demonstrates how the energy depends on a Landau level lling factor (i.e., density). Providing the tunneling current is proportional to the derivative dn=d the non-monotonic behavior of this dependence implies the existence of singularities of tunneling current for = 1/2 and = 1. This e ect at some rate reminds the Fractional Quantum Hall E ect. The occurrence of non-monotonic function ( ) merely originates in strong exponential dependence of the exchange overlap integral on the distance between interacting electrons.

4 Conclusion

Tunnelling density of states in the vicinity of Fermi level of a two-dimensional electron gas subjected to an external parallel and zero magnetic eld is calculated. It reveals a pseudo-gap recently observed in the experiments. The gap originates in spin polarization of 2DEG. Non-monotonic dependence of energy on a Landau level lling factor (density) was also obtained. It makes possible the tunneling current peculiarities at lling factors 1/2 and 1. The Ising-like model of the exchange interaction in 2DEG exploited instead of the conventional one is crucial to achieve even a qualitative agreement with experimental data.

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